

Geoffrey K Bradshaw

List of Publications by Year in descending order

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Version: 2024-02-01

18
papers

100
citations

1684188

5
h-index

1720034

7
g-index

18
all docs

18
docs citations

18
times ranked

91
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | Crack-Tolerant Metal Composites as Photovoltaic Gridlines. IEEE Journal of Photovoltaics, 2019, 9, 1754-1758. | 2.5 | 5 |
| 2 | Light trapping structures for radiation hardness enhancement of space solar cells. Solar Energy Materials and Solar Cells, 2018, 182, 136-141. | 6.2 | 15 |
| 3 | Simulation of Light Trapping Structures for Enhancing Radiation Hardness in Space Solar Cells. , 2017, , . | | 1 |
| 4 | Quantitative Electroluminescence Analysis of Triple Junction Solar Cells to Determine Subcell Voltage-Temperature Coefficients. , 2017, , . | | 0 |
| 5 | Integration of crack-tolerant composite gridlines on triple junction photovoltaic cells. , 2017, , . | | 1 |
| 6 | Spray-coated carbon-nanotubes for crack-tolerant metal matrix composites as photovoltaic gridlines. , 2016, , . | | 4 |
| 7 | Post-flight analysis of MISSE-8 advanced photovoltaic technologies. , 2015, , . | | 0 |
| 8 | Stability of isotope reference cells used for multi-source solar simulator calibration. , 2015, , . | | 0 |
| 9 | Flight results for the passive MISSE 7 Coatings and Coverglass Panel experiment. , 2015, , . | | 0 |
| 10 | GaInP/GaAs Tandem Solar Cells With InGaAs/GaAsP Multiple Quantum Wells. IEEE Journal of Photovoltaics, 2014, 4, 614-619. | 2.5 | 9 |
| 11 | Effect of GaAs interfacial layer on the performance of high bandgap tunnel junctions for multijunction solar cells. Applied Physics Letters, 2013, 103, . | 3.3 | 26 |
| 12 | Determination of carrier recombination lifetime in InGaAs quantum wells from external quantum efficiency measurements. , 2013, , . | | 1 |
| 13 | Carrier Transport and Improved Collection in Thin-Barrier InGaAs/GaAsP Strained Quantum Well Solar Cells. IEEE Journal of Photovoltaics, 2013, 3, 278-283. | 2.5 | 23 |
| 14 | Tandem InGaP/GaAs-quantum well solar cells and their potential improvement through phosphorus carry-over management in multiple quantum well structures. , 2013, , . | | 0 |
| 15 | Modeling an InGaP/AlGaAs tunnel junction containing an AlAs diffusion barrier. , 2013, , . | | 0 |
| 16 | Interface properties of Ga(As,P)/(In,Ga)As strained multiple quantum well structures. Applied Physics Letters, 2013, 103, . | 3.3 | 11 |
| 17 | The optimization of high indium and high phosphorus content InGaAs/GaAsP strained layer superlattices for use in multijunction solar cells. , 2012, , . | | 1 |
| 18 | Effects of Barrier Width on Spectral Response of Strained Layer Superlattices for High Efficiency Solar Cells. Materials Research Society Symposia Proceedings, 2009, 1211, 1. | 0.1 | 3 |